### 1. General description

NPN/NPN general-purpose transistor pair in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- Low collector capacitance
- · Low collector-emitter saturation voltage
- · Closely matched current gain
- · Reduces number of components and board space
- No mutual interference between the transistors
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

### 3. Applications

· General-purpose switching and amplification

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor					•	
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	65	V
I <sub>C</sub>	collector current		-	-	100	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$	200	300	450	



### 65 V, 100 mA NPN/NPN general-purpose transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1	6 5 4	
3	C2	collector TR2		(TR1) TR2)
4	E2	emitter TR2		
5	B2	base TR2	☐1 ☐2 ☐3	I I I E1 B1 C2
6	C1	collector TR1	TSSOP6 (SOT363)	sym020

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
BC846BS-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363			

### 7. Marking

### Table 4. Marking codes

Type number	Marking code[1]
BC846BS-Q	%E5

[1] % = placeholder for manufacturing site code

### 65 V, 100 mA NPN/NPN general-purpose transistor

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		•	'		
V <sub>CBO</sub>	collector-base voltage	open emitter		-	80	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	65	V
$V_{EBO}$	emitter-base voltage	open collector		-	6	V
I <sub>C</sub>	collector current			-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	200	mA
I <sub>BM</sub>	peak base current			-	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
Per device						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

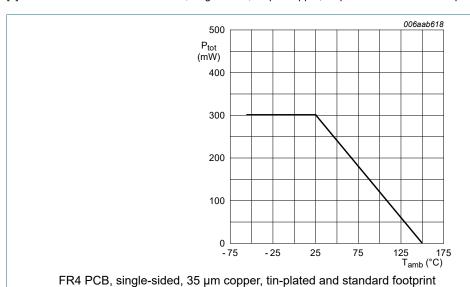


Fig. 1. Per device: Power derating curve SOT363 (SC-88)

#### 65 V, 100 mA NPN/NPN general-purpose transistor

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	230	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35  $\mu m$  copper, tin-plated and standard footprint.

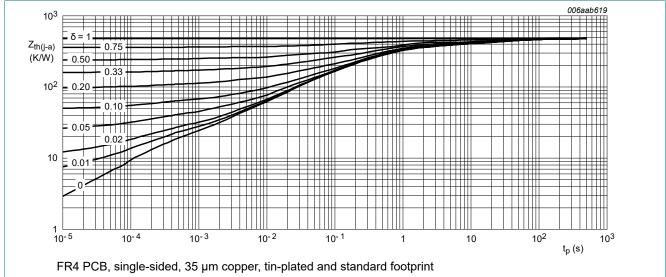


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 65 V, 100 mA NPN/NPN general-purpose transistor

# 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	80	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	65	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	$I_C = 0 \text{ A}; I_E = 100 \mu\text{A}; T_{amb} = 25 \text{ °C}$	6	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	15	nA
	current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 6 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 μA; T <sub>amb</sub> = 25 °C	-	280	-	
		V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 mA; T <sub>amb</sub> = 25 °C	200	300	450	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA; T <sub>amb</sub> = 25 °C	-	55	100	mV
		I <sub>C</sub> = 100 mA; I <sub>B</sub> = 5 mA; T <sub>amb</sub> = 25 °C	-	200	300	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA; T <sub>amb</sub> = 25 °C	-	755	850	mV
		I <sub>C</sub> = 100 mA; I <sub>B</sub> = 5 mA; T <sub>amb</sub> = 25 °C	-	1000	-	mV
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 mA; T <sub>amb</sub> = 25 °C	580	650	700	mV
		V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	-	770	mV
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$	-	1.9	-	pF
C <sub>e</sub>	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_{C} = 0 \text{ A}; i_{c} = 0 \text{ A};$ $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$	-	11	-	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	100	-	-	MHz
NF	noise figure	$V_{CE}$ = 5 V; $I_{C}$ = 0.2 mA; $R_{S}$ = 2 k $\Omega$ ; 10 Hz ≤ f ≤ 15700 Hz; $T_{amb}$ = 25 °C	-	1.9	-	dB
		$V_{CE}$ = 5 V; $I_{C}$ = 0.2 mA; $R_{S}$ = 2 k $\Omega$ ; $f$ = 1 kHz; $B$ = 200 Hz; $T_{amb}$ = 25 °C	-	3.1	-	dB
		ı .				

#### 65 V, 100 mA NPN/NPN general-purpose transistor

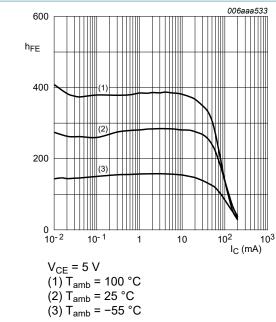


Fig. 3. Per transistor: DC current gain as a function of collector current; typical values

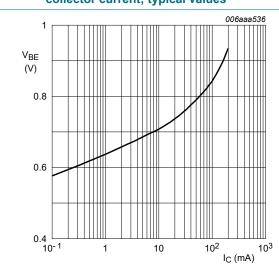


Fig. 5. Per transistor: Base-emitter voltage as a function of collector current; typical values

 $V_{CE}$  = 5 V;  $T_{amb}$  = 25 °C

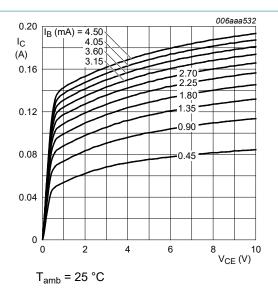
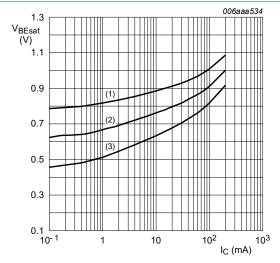


Fig. 4. Per transistor: Collector current as a function of collector-emitter voltage; typical values



 $I_{\rm C}/I_{\rm B} = 20$ 

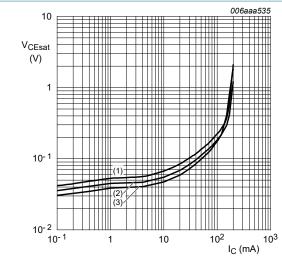
(1)  $T_{amb} = -55$  °C

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 6. Per transistor: Base-emitter saturation voltage as a function of collector current; typical values

#### 65 V, 100 mA NPN/NPN general-purpose transistor



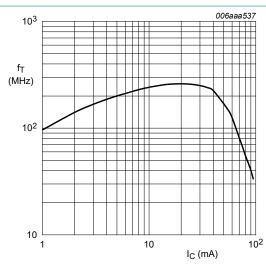
$$I_C/I_B = 20$$

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(1) 
$$T_{amb} = 160^{\circ} \text{ C}$$
  
(2)  $T_{amb} = 25^{\circ} \text{ C}$   
(3)  $T_{amb} = -55^{\circ} \text{ C}$ 

Fig. 7. Per transistor: Collector-emitter saturation voltage as a function of collector current; typical values



 $V_{CE}$  = 5 V;  $T_{amb}$  = 25 °C

Fig. 8. Per transistor: Transition frequency as a function of collector current; typical values

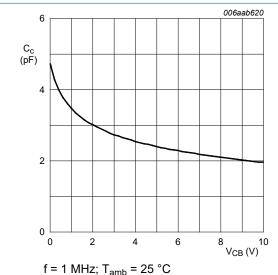


Fig. 9. Per transistor: Collector capacitance as a function of collector-base voltage; typical values

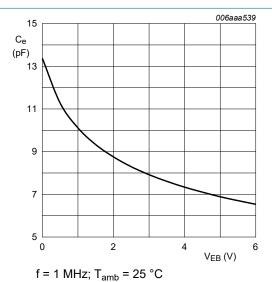


Fig. 10. Per transistor: Emitter capacitance as a function of emitter-base voltage; typical values

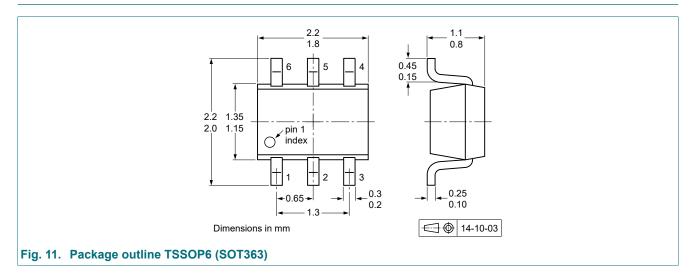
#### 11. Test information

#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

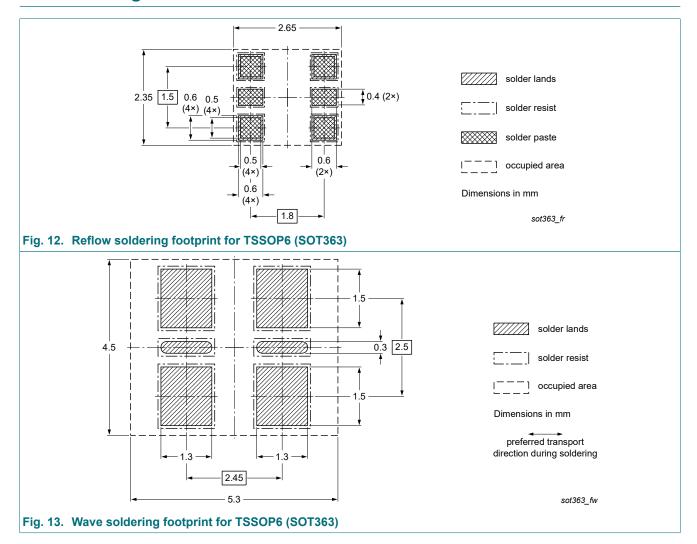
### 65 V, 100 mA NPN/NPN general-purpose transistor

# 12. Package outline



### 65 V, 100 mA NPN/NPN general-purpose transistor

# 13. Soldering



## 65 V, 100 mA NPN/NPN general-purpose transistor

# 14. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC846BS-Q v.1	20210617	Product data sheet	-	-

### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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For more information, please visit: http://www.nexperia.com
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Date of release: 17 June 2021

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